



**Surface Mount Package** 

# Silicon Epitaxial Planar Diode High Voltage Switching Diode

# 1N3004W

**RoHS compliant** 

**SOD-123** 

	JX	-
1		

SOD-123

Top View PIN DESCRIPTION 1. Cathode 2. Anode

Marking Code :JX **FEATURES:** 

1.Fast switching speed

2 High Conductance

3. High Reverse Breakdown Voltage

APPLICATIONS: High Voltage Switching

### **ABSOLUTE MAXIMUM RATINGS** (T<sub>a</sub>=25°C unless otherwise noted)

Parameter			Value	Unit	
Repetitive Peak Reverse Voltage		V <sub>RRM</sub>	350	V	
Working Peak Reverse Voltage		V <sub>RWM</sub>	300	V	
Reverse Voltage			300	V	
Continues Forward Current			225	mA	
Peak Repetitive Forward Current		I <sub>FRM</sub>	625	mA	
Non-Repetitive Peak Forward Surge Current	at t = 1 µs	I <sub>FSM</sub>	4	А	
Non-Repetitive Peak Forward Surge Current	at t = 1 s		1		
Power Dissipation	•	Pd	350	mW	
Operating and Storage Temperature Range			- 65 to + 150	°C	





# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub>=25 °C unless otherwise Specified)

PARAMETER	Symbol	TEST CONDITIONS	VALUE			UNIT
PARAMETER	Symbol	TEST CONDITIONS	MIN	TYP.	MAX	UNIT
		at I <sub>F</sub> = 20 mA			0.87	
Forward Voltage	V <sub>F</sub>	at I <sub>F</sub> = 100 mA			1	V
		at I <sub>F</sub> = 200 mA			1.25	
	I <sub>R</sub>	at V <sub>R</sub> = 240 V			100	nA
Reverse Current		at V <sub>R</sub> = 240 V, T <sub>J</sub> =150° C			100	uA
Reverse Breakdown Voltage	V <sub>(BR)R</sub>	at I <sub>R</sub> = 100 µA	350			V
Total Capacitance	C <sub>T</sub>	at $V_R$ = 0, f = 1 MHz			5	pF
Reverse Recovery Time	t <sub>rr</sub>	at I <sub>F</sub> = I <sub>R</sub> = 30 mA, i <sub>rr</sub> = 0.1 I, R <sub>L</sub> =100Ω			50	nS





1600

10

100

2000

## **Typical Characteristic Curves**

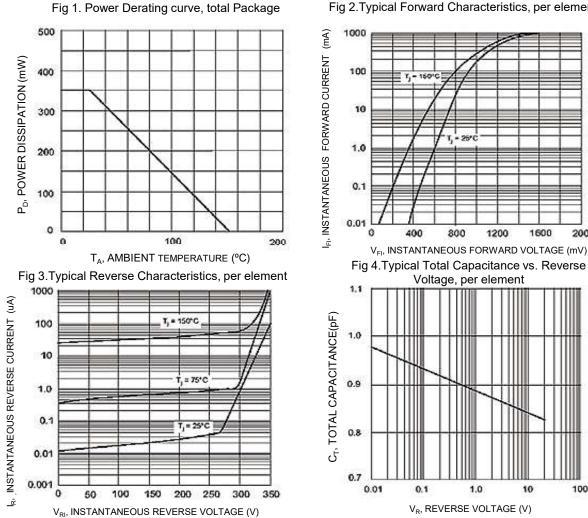


Fig 2.Typical Forward Characteristics, per element

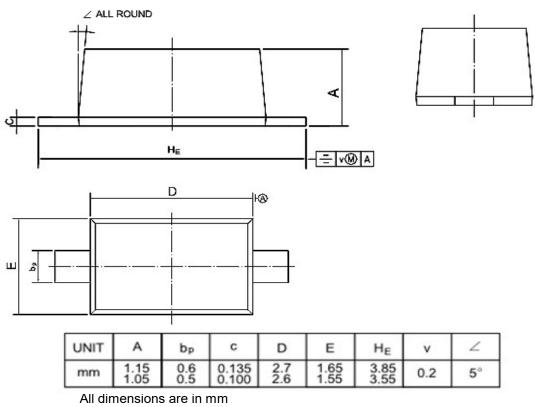
1N3004W Rev0\_23042020EGL



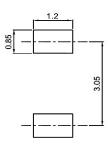


## PACKGE DETAILS

SOD-123 Surface Mount Package



# **Recommended Soldering Footprint**



1N3004W Rev0\_23042020EGL





# Recommended Product Storage Environment for Discrete Semiconductor Devices

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- · Temperature 5 °C to 30 °C
- · Humidity between 40 to 70 %RH
- · Air should be clean.
- · Avoid harmful gas or dust.
- · Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- · Avoid rapid change of temperature.
- · Avoid condensation.
- · Mechanical stress such as vibration and impact shall be avoided.
- · The product shall not be placed directly on the floor.
- $\cdot\,$  The product shall be stored on a plane area. They should not be turned upside down.
- They should not be placed against the wall.

#### Shelf Life of CDIL Products

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years. If products are stored longer than the shelf life of 2 years the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

#### Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start. For this, the following JEDEC table may be referred:

JEDEC MSL Level				
Level	Time	Condition		
1	Unlimited	≤30 °C / 85% RH		
2	1 Year	≤30 °C / 60% RH		
2a	4 Weeks	≤30 °C / 60% RH		
3	168 Hours	≤30 °C / 60% RH		
4	72 Hours	≤30 °C / 60% RH		
5	48 Hours	≤30 °C / 60% RH		
5a	24 Hours	≤30 °C / 60% RH		
6	Time on Label(TOL)	≤30 °C / 60% RH		

1N3004W Rev0\_23042020EGL





## **Customer Notes**

### **Component Disposal Instructions**

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

### Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is commended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).



#### Continental Device India Pvt. Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India. Telephone +91-11-2579 6150, 4141 1112 Fax +91-11-2579 5290, 4141 1119 email@cdil.com www.cdil.com CIN No. U32109DL1964PTC004291

1N3004W Rev0\_23042020EGL

Continental Device India Pvt. Limited Data Sheet